TOSHIBA HIGH EFFICIENCY DIODE STACK (HED) SILICON EPITAXIAL TYPE

20 J L 2 C 4 1

SWITCHING TYPE POWER SUPPLY APPLICATION CONVERTER & CHOPPER APPLICATION

• Repetitive Peak Reverse Voltage : V_{RRM}=600V

Average Output Rectified Current : I_O=20A

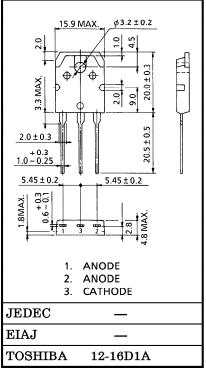
• Ultra Fast Reverse-Recovery Time : t_{rr}=50ns (Max.)

• Low Switching Losses and Output Noise.

MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Repetitive Peak Reverse Voltage	V_{RRM}	600	V	
Average Output Rectified Current	I_{O}	20	Α	
Peak One Cycle Surge Forward	Traces	100 (50Hz)	1 A 1	
Current (Sine Wave)	IFSM	110 (60Hz)		
Junction Temperature	T_j	-40~150	$^{\circ}\mathrm{C}$	
Storage Temperature Range	$ m T_{stg}$	-40~150	$^{\circ}\mathrm{C}$	
Screw Torque	_	0.8	N∙m	

Unit in mm



Weight: 4.85g

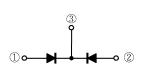
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

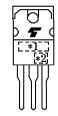
CHARACTERISTIC	SYMBOL	TEST CONDITION	TYP.	MAX.	UNIT	
Peak Forward Voltage (Note 1)	$V_{\mathbf{FM}}$	I _{FM} =10A	_	2.0	V	
Repetitive Peak Reverse Current (Note 1)	I_{RRM}	$V_{ m RRM}$ =600V	_	50	μ A	
Reverse Recovery time (Note 1)	t _{rr}	$I_{\rm F}$ =2A, di/dt=-50A/ μ s	1	50	ns	
Forward Recovery time (Note 1)	t_{fr}	$I_{\mathbf{F}} = 1\mathbf{A}$	_	150	ns	
Thermal Resistance	R _{th (j-c)}	DC Total, Junction to Case	_	1.5	°C/W	

Note 1: A value of one cell.

POLARITY

MARKING

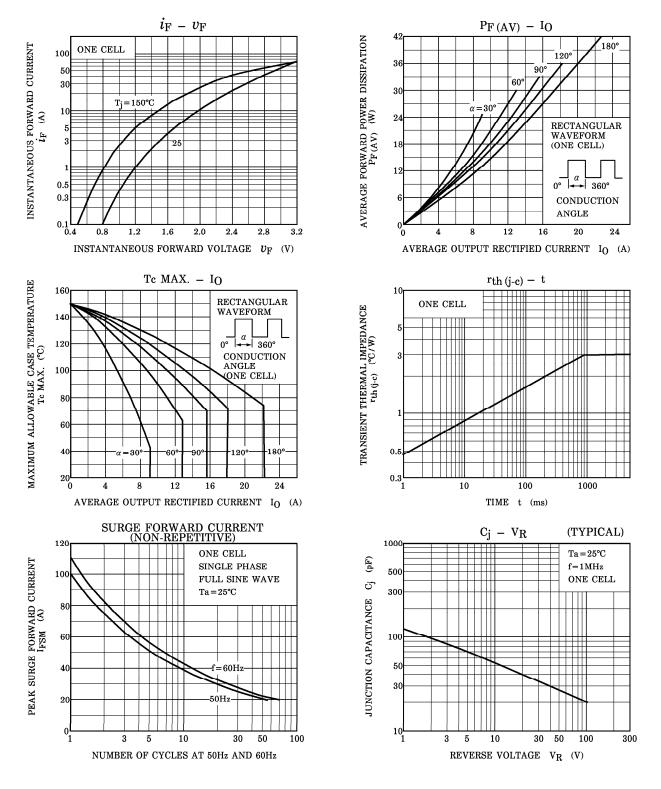




*1	MARK	20JL2C	
*2	Lot Number		

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